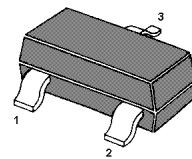


MMBTSC2714

NPN Silicon Epitaxial Planar Transistor

for high frequency amplifier at FM,RF,MIX, and IF
amplifier applications.

The transistor is subdivided into three groups, R,
O and Y, according to its DC current gain.



1. Base 2. Emitter 3. Collector

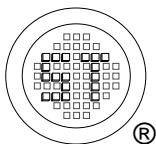
TO-236 Plastic Package

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

| Parameter | Symbol | Value | Unit |
|---------------------------|-----------|---------------|------|
| Collector Base Voltage | V_{CBO} | 40 | V |
| Collector Emitter Voltage | V_{CEO} | 30 | V |
| Emitter Base Voltage | V_{EBO} | 4 | V |
| Collector Current | I_C | 20 | mA |
| Base Current | I_B | 4 | mA |
| Power Dissipation | P_{tot} | 200 | mW |
| Junction Temperature | T_j | 125 | °C |
| Storage Temperature Range | T_{stg} | - 55 to + 125 | °C |

Characteristics at $T_{amb}=25^\circ\text{C}$

| Parameter | Symbol | Min. | Typ. | Max. | Unit |
|---|---------------|----------|------|------|------|
| DC Current Gain at $V_{CE} = 6 \text{ V}$, $I_C = 1 \text{ mA}$ Current Gain Group | R | h_{FE} | 40 | - | 80 |
| | O | h_{FE} | 70 | - | 140 |
| | Y | h_{FE} | 100 | - | 200 |
| Collector Base Cutoff Current at $V_{CB} = 18 \text{ V}$ | I_{CBO} | - | - | 500 | nA |
| Emitter Base Cutoff Current at $V_{EB} = 4 \text{ V}$ | I_{EBO} | - | - | 500 | nA |
| Collector Base Breakdown Voltage at $I_C = 100 \mu\text{A}$ | $V_{(BR)CBO}$ | 40 | - | - | V |
| Collector Emitter Breakdown Voltage at $I_C = 1 \text{ mA}$ | $V_{(BR)CEO}$ | 30 | - | - | V |
| Emitter Base Breakdown Voltage at $I_E = 100 \mu\text{A}$ | $V_{(BR)EBO}$ | 4 | - | - | V |
| Collector Emitter Saturation Voltage at $I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$ | $V_{CE(sat)}$ | - | - | 0.5 | V |
| Transition Frequency at $V_{CE} = 6 \text{ V}$, $I_C = 1 \text{ mA}$ | f_T | - | 550 | - | MHz |
| Reverse Transfer Capacitance at $V_{CB} = 6 \text{ V}$, $f = 1 \text{ MHz}$ | C_{re} | - | 0.7 | - | pF |

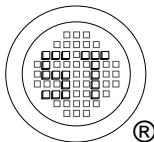
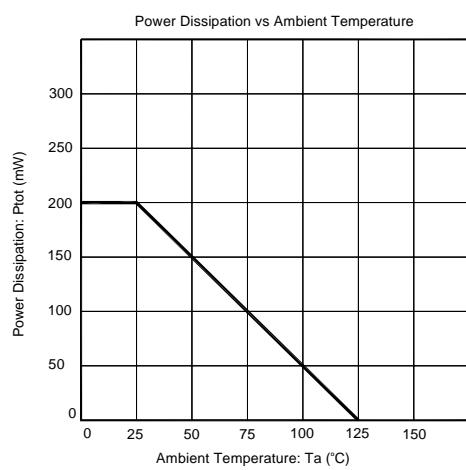
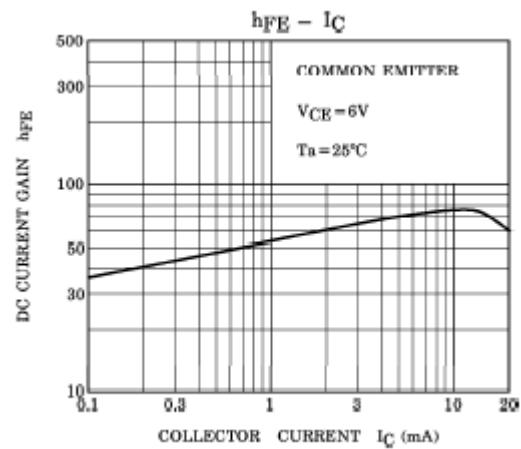
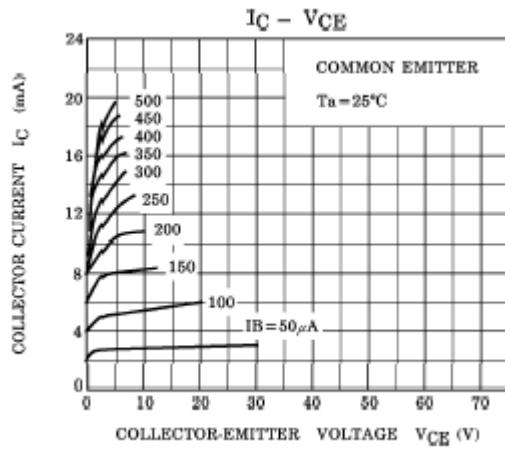


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ISO9001 : 2008 Certificate No. 160719000 ISO14001 : 2004 Certificate No. 7116 ISO9001 : 2008 Certificate No. 50713410 BS-OHSAS 18001 : 2007 Certificate No. 7116 IECQ QC 080000 Certificate No. PRC-HSPM-14034 SGS

Dated: 16/03/2015 Rev: 01



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